

Package : SOT-25

Epitaxial planar PNP/NPN silicon transistor

Descriptions

• Complex type bipolar transistor

Features

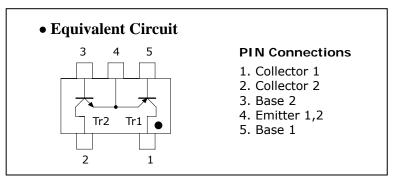
- Reduce quantity of parts and mounting cost
- High collector power dissipation : $P_c = 300 \text{mW}(\text{Max.})$
- Both 2SA1980 chip and 2SC5343 chip in SOT-25 package

Ordering Information

Туре NO.	Marking	Package Code
SUT464M	X4 🗆	SOT-25

: Year & Week Code

Equivalent circuit & PIN Connections



Absolute Maximum Ratings [Tr1, Tr2]

(Ta=25°C)

Characteristic	Symbol	Rating		Unit	
Characteristic	Symbol	Tr1	Tr2	Unit	
Collector-base voltage	V _{CBO}	-50	60	V	
Collector-emitter voltage	V _{CEO}	-50	50	V	
Emitter-base voltage	V _{EBO}	-5	5	V	
Collector current	I _C	-150	150	mA	
Collector Power dissipation	P _C *	300		mW	
Junction temperature	T ₁	150		°C	
Storage temperature range	T _{stg}	-55~150		°C	

ℜ: Total rating

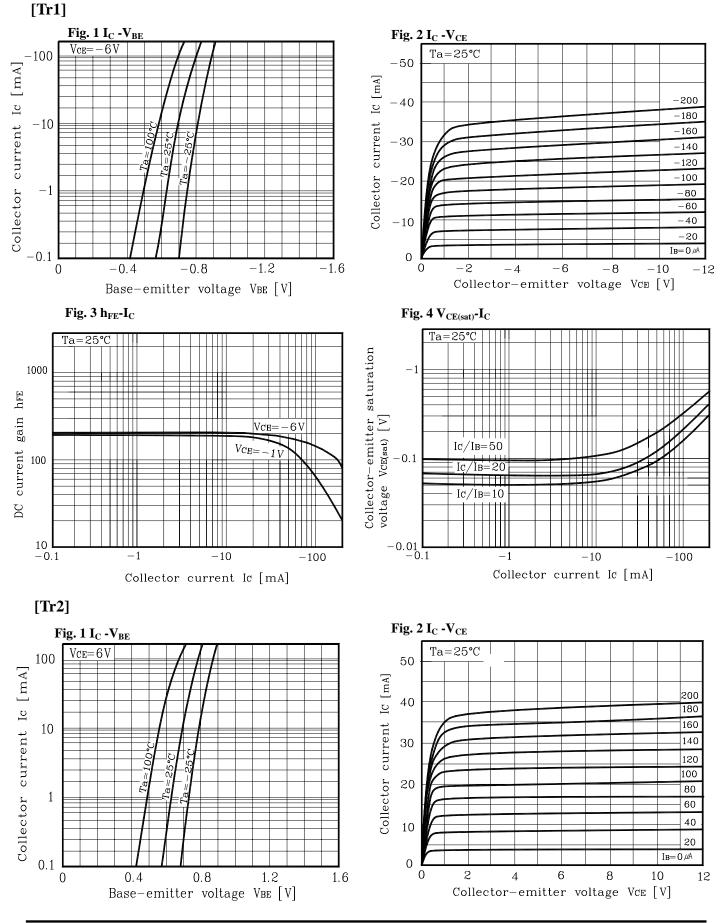
Electrical Characteristics [Tr1]

Electrical Characteristics [Tr1] (Ta=25						=25°C)
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C =-1mA, I _B =0	-50	-	-	V
Collector cut-off current	I_{CBO}	V_{CB} =-50V, I_{E} =0	-	-	-0.1	μA
Emitter cut-off current	\mathbf{I}_{EBO}	V_{EB} =-5V, I _C =0	-	-	-0.1	μA
DC current gain	h _{FE}	V_{CE} =-6V, I _C =-2mA	120	-	400	-
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	I_{C} =-100mA, I_{B} =-10mA	-	-	-0.3	V
Base-emitter voltage	V_{BE}	V_{CE} =-6V, I _C =-2mA	-	-0.65	-	V
Transition frequency	f⊤	V_{CE} =-10V, I _C =-10mA	-	200	-	MHz
Collector output capacitance	C _{ob}	V_{CB} =-10V, I_E =0, f=1MHz	-	4	-	pF

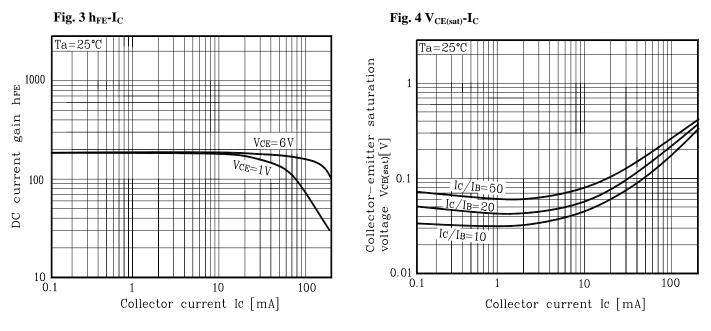
Electrical Characteristics [Tr2]

Electrical Characteristics [Tr2] (Ta=2						=25°C)
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	$I_{C}=1mA$, $I_{B}=0$	50	-	-	V
Collector cut-off current	I_{CBO}	V_{CB} =60V, I_{E} =0	-	-	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} =5V, I_C =0	-	-	0.1	μA
DC current gain	h _{FE}	V_{CE} =6V, I _C =2mA	120	-	400	-
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	I_{C} =100mA, I_{B} =10mA	-	-	0.25	V
Base-emitter voltage	V_{BE}	V_{CE} =6V, I _C =2mA	-	0.65	-	V
Transition frequency	f⊤	V_{CE} =10V, I_{C} =10mA	-	200	-	MHz
Collector output capacitance	C _{ob}	V_{CB} =10V, I_E =0, f=1MHz	-	2	-	pF

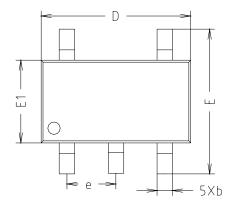
Electrical Characteristic Curves

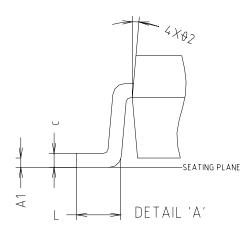


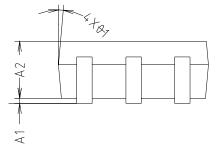
Electrical Characteristic Curves

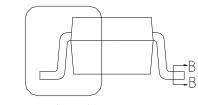


SOT-25 Outline Dimension(mm)





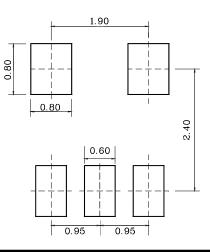






SYMBOL		NOTE		
	MINIMUM	NOMINAL	MAXIMUM	NOTE
A1	0.000	0.050	0.100	
A2	1.000	1.100	1.200	
С	0.110	0.150	0.190	
с1	0.085	0.125	0.165	
D	2.800	2.900	3.000	
E	2.600	2.800	3.000	
E1	1.500	1.600	1.700	
е	0.930	0.950	0.970	
L	0.400	-	-	
θ1		5° REF		
θ2		5° REF		

* Recommend PCB solder land [Unit: mm]



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